Low-power dual supply buffer/line driver; 3-state Rev. 01 — 1 July 2009

Product data sheet

General description 1.

The 74AUP2T1326 is a high-performance, dual supply, low-power, low-voltage, dual buffer/line driver with output enable circuitry.

The 74AUP2T1326 is designed for logic-level translation and combines the functions of the 74AUP1G32 and 74AUP2G126. The buffer/line driver is controlled by two output enable inputs (1OE and 2OE). A logic LOW on input 1OE causes the output 2Y to assume a high-impedance OFF-state, a logic LOW on 2OE causes the output 3Y to assume a high-impedance OFF-state. The output 1Y is the result of a logic OR of the two output enable inputs.

The output enable inputs (1OE and 2OE) are Schmitt trigger inputs, they switch at different voltages for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_H. The output enable inputs accept standard input signals and are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals

Both $V_{CC(A)}$ and $V_{CC(B)}$ can be supplied at any voltage between 1.1 V and 3.6 V making the device suitable for interfacing between any of the low voltage nodes (1.2 V, 1.5 V, 1.8 V, 2.5 V and 3.3 V) with compatible input levels. Pins 1OE, 2OE and 1Y are referenced to V_{CC(A)} and pins A, 2Y and 3Y are referenced to V_{CC(B)}.

The device ensures low static and dynamic power consumption and is fully specified for partial power down applications using IOFF. The IOFF circuitry disables the outputs, preventing any damaging backflow current through the device when it is powered down.

Features 2.

- Wide supply voltage range:
 - V_{CC(A)}: 1.1 V to 3.6 V; V_{CC(B)}: 1.1 V to 3.6 V.
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114E Class 2A exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101C exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \,\mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II



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- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from –40 °C to +85 °C

3. Ordering information

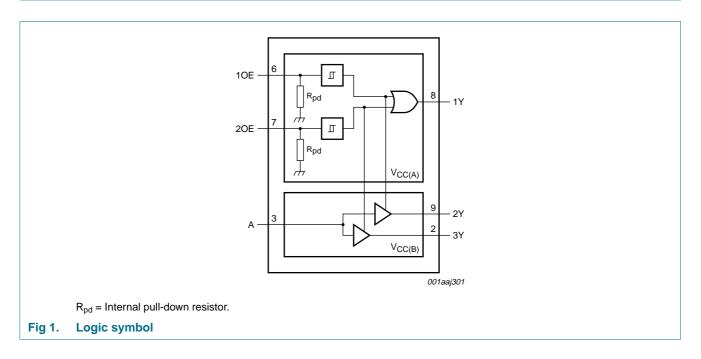
| Type number | Package | | | | | | | | | |
|---------------|-------------------|---------|--|-----------|--|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | | |
| 74AUP2T1326GF | –40 °C to +85 °C | XSON10U | plastic extremely thin small outline package; no leads; 10 terminals; UTLP based; body 1 x 1.7 x 0.5 mm | SOT1081-1 | | | | | | |

4. Marking

| Table 2. Marking | |
|------------------|-----------------------------|
| Type number | Marking code ^[1] |
| 74AUP2T1326GF | pf |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

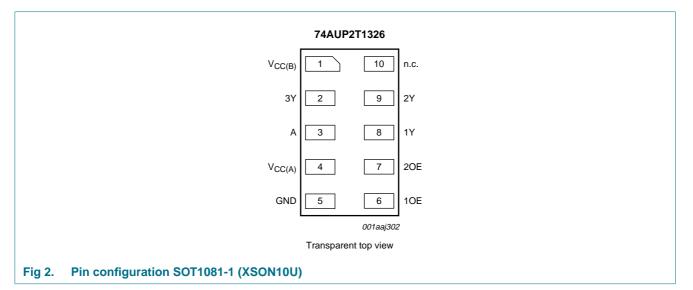
5. Functional diagram



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6. Pinning information

6.1 Pinning



6.2 Pin description

| Table 3. | Pin description | |
|--------------------|-----------------|---|
| Symbol | Pin | Description |
| V _{CC(B)} | 1 | supply voltage B |
| 3Y | 2 | data output |
| A | 3 | data input |
| V _{CC(A)} | 4 | supply voltage A |
| GND | 5 | ground (0 V) |
| 10E | 6 | output enable input (Schmitt trigger input) |
| 20E | 7 | output enable input (Schmitt trigger input) |
| 1Y | 8 | data output |
| 2Y | 9 | data output |
| n.c. | 10 | not connected |

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7. Functional description

| Table 4. F | unction table ^[1] | | | | | | |
|------------|------------------------------|---|--------|--------|----|--|--|
| Input | | | Output | Output | | | |
| 10E | 20E | A | 1Y | 2Y | 3Y | | |
| L | L | Х | L | Z | Z | | |
| L | Н | L | Н | Z | L | | |
| L | Н | Н | Н | Z | Н | | |
| Н | L | L | Н | L | Z | | |
| Н | L | Н | Н | Н | Z | | |
| Н | Н | L | Н | L | L | | |
| Н | Н | Н | Н | Н | Н | | |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| | | | | | / |
|--------------------|-------------------------|--|-----------------|------|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| V _{CC(A)} | supply voltage A | | -0.5 | +4.6 | V |
| V _{CC(B)} | supply voltage B | | -0.5 | +4.6 | V |
| I _{IK} | input clamping current | V ₁ < 0 V | -50 | - | mA |
| VI | input voltage | | <u>[1]</u> –0.5 | +4.6 | V |
| I _{ОК} | output clamping current | V _O < 0 V | <u>[2]</u> –50 | - | mA |
| Vo | output voltage | Active mode and Power-down mode | <u>[1]</u> –0.5 | +4.6 | V |
| lo | output current | $V_{O} = 0 V$ to V_{CCO} | [2] _ | ±20 | mA |
| I _{CC} | supply current | | - | 50 | mA |
| I _{GND} | ground current | | -50 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \ ^{\circ}C$ to +85 $^{\circ}C$ | <u>[3]</u> | 250 | mW |
| | | | | | |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] V_{CCO} is the supply voltage associated with an output pin.

[3] For XSON10U package: above 45 $^\circ$ C the value of P_{tot} derates linearly with 2.4 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|--------------------|------------------|------------|--------------|------------------|------|
| V _{CC(A)} | supply voltage A | | 1.1 | 3.6 | V |
| V _{CC(B)} | supply voltage B | | 1.1 | 3.6 | V |
| VI | input voltage | | 0 | 3.6 | V |
| Vo | output voltage | | <u>[1]</u> 0 | V _{cco} | V |

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| lable 6. | Recommended operating conditi | onscontinued | | | |
|-----------------------|-------------------------------------|---|-------|-----|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| T _{amb} | ambient temperature | | -40 | +85 | °C |
| $\Delta t / \Delta V$ | input transition rise and fall rate | input A; V_{CCI} = 1.1 V to 3.6 V | [2] _ | 200 | ns/V |
| | | input nOE; V _{CCI} = 1.1 V to 3.6 V | [2] - | 30 | ms/V |

T ~ 2.5

[1] V_{CCO} is the supply voltage associated with an output pin.

[2] V_{CCI} is the supply voltage associated with an input pin.

10. Static characteristics

Table 7. **Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | | 25 °C | | –40 °C to | C to +85 °C | |
|------------------|---------------------------------|--|---------------|-------------------|-------|---------------|------------------------|---------------|----|
| | | | | Min | Тур | Max | Min | Max | |
| V _{IH} | HIGH-level | input A; | <u>[1][3]</u> | | | | | | |
| | input voltage | V _{CCI} = 1.65 V to 1.95 V | | $0.65V_{CCI}$ | - | - | $0.65V_{CCI}$ | - | V |
| | vollage | V_{CCI} = 2.3 V to 2.7 V | | 1.6 | - | - | 1.6 | - | V |
| V _{IL} | LOW-level | input A; | [1][3] | | | | | | |
| | input voltage | V _{CCI} = 1.65 V to 1.95 V | | - | - | $0.35V_{CCI}$ | - | $0.35V_{CCI}$ | V |
| voltage | vollage | V_{CCI} = 2.3 V to 2.7 V | | - | - | 0.7 | - | 0.7 | V |
| V _{OH} | HIGH-level | $V_I = V_{IL} \text{ or } V_I \text{ or } V_I = V_{T+} \text{ or } V_{T-}$ | | | | | | | |
| - | output voltage | I _O = -20 μA; V _{CCO} = 1.65 V to 2.7 V | [2] | $V_{\rm CCO}-0.1$ | - | - | V _{CCO} – 0.1 | - | V |
| | | $I_{O} = -3 \text{ mA}; V_{CCO} = 1.65 \text{ V}$ | | 1.2 | - | - | 1.2 | - | V |
| | | I_{O} = -2.3 mA; V_{CCO} = 2.3 V | | 1.97 | - | - | 1.97 | - | V |
| | | I_{O} = -4.0 mA; V_{CCO} = 2.3 V | | 2.0 | - | - | 2.0 | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{IL} \text{ or } V_I \text{ or } V_I = V_{T+} \text{ or } V_{T-}$ | [2] | | | | | | |
| | | I _O = 20 μA; V _{CCO} = 1.65 V to 2.7 V | | - | - | 0.10 | - | 0.10 | V |
| | | $I_{O} = 3.0 \text{ mA}; V_{CCO} = 1.65 \text{ V}$ | | - | - | 0.45 | - | 0.45 | V |
| | | I_{O} = 2.3 mA; V_{CCO} = 2.3 V | | - | - | 0.33 | - | 0.33 | V |
| | | I_{O} = 4.0 mA; V_{CCO} = 2.3 V | | - | - | 0.40 | - | 0.40 | V |
| lı | input leakage current | input A; $V_1 = 0$ V to 2.7 V; $V_{CCI} = 1.65$ V to 2.7 V | <u>[1]</u> | - | - | ±0.1 | - | ±0.5 | μΑ |
| I _{OZ} | OFF-state output current | | | - | - | ±0.1 | - | ±0.5 | μΑ |
| I _{OFF} | power-off leakage current | | | - | - | ±0.2 | - | ±0.5 | μΑ |
| | | A, 2Y, 3Y; $V_{CC(B)} = 0$ V; V ₁ or V ₀ = 0 V to 2.7 V; $V_{CC(A)} = 1.65$ V to 2.7 V | | - | - | ±0.2 | - | ±0.5 | μΑ |

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Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | | 25 °C | | –40 °C to | Unit | |
|--------------------|--|--|------------|-----|-------|------|-----------|------|----|
| | | | | Min | Тур | Max | Min | Мах | |
| ΔI _{OFF} | ∆l _{OFF} additional power-off leakage | $\begin{array}{l} 1 \text{Y; } \text{V}_{\text{CC}(\text{A})} = 0 \text{ V to } 0.2 \text{ V;} \\ \text{V}_{\text{O}} = 0 \text{ V to } 2.7 \text{ V;} \\ \text{V}_{\text{CC}(\text{B})} = 1.65 \text{ V to } 2.7 \text{ V} \end{array}$ | | - | - | ±0.2 | - | ±0.6 | μA |
| CUR | current | A, 2Y, 3Y; $V_{CC(B)} = 0 V \text{ to } 0.2 V;$ $V_{I} \text{ or } V_{O} = 0 V \text{ to } 2.7 V;$ $V_{CC(A)} = 1.65 V \text{ to } 2.7 V$ | | - | - | ±0.2 | - | ±0.6 | μA |
| I _{CC(A)} | supply | $V_I = 0 V \text{ or } V_{CC(A)}; I_O = 0 A$ | <u>[1]</u> | | | | | | |
| | current A | $V_{CC(A)} = 1.65$ V to 2.7 V; $V_{CC(B)} = 0$ V to 2.7 V | | - | - | 0.5 | - | 0.9 | μA |
| (-) | supply | $V_I = 0 V \text{ or } V_{CC(B)}; I_O = 0 A$ | <u>[1]</u> | | | | | | |
| | current B | $V_{CC(A)} = V_{CC(B)} = 1.65 \text{ V to}$ 2.7 V; | | - | - | 0.5 | - | 0.9 | μA |
| | | $V_{CC(A)} = 1.71 \text{ V}; V_{CC(B)} = 2.6 \text{ V}$ | | - | - | 500 | - | 750 | μΑ |
| ΔI_{CC} | additional supply current | $\begin{array}{l} nOE; V_{CC(A)} = V_{CC(B)} = 2.7 \ V; \\ V_{I} = V_{CC(A)} - 0.6 \ V \end{array}$ | | - | - | 40 | - | 50 | μA |
| | | A; $V_{CC(A)} = V_{CC(B)} = 2.7 \text{ V};$ $V_I = V_{CC(B)} - 0.6 \text{ V};$ | | - | - | 80 | - | 100 | μA |
| | | A; $V_I = GND$ to 2.7 V; nOE = GND; $V_{CC(A)} = 1.65$ V to 2.7 V; $V_{CC(B)} = 1.65$ V to 2.7 V | [4] | - | - | 2 | - | 2 | μA |
| R _{pd} | pull-down resistance | | | 145 | 200 | 255 | 140 | 260 | kΩ |
| CI | input capacitance | input A; V _I = 0 V or V _{CCI} ; V _{CCI} = 1.65 V to 2.7 V | <u>[1]</u> | - | 0.9 | - | - | - | pF |
| | | input nOE; $V_I = 0 V \text{ or } V_{CCI}$; $V_{CCI} = 1.65 V \text{ to } 2.7 V$ | <u>[1]</u> | - | 0.8 | - | - | - | pF |
| Co | output | 1Y; $V_0 = GND$; $V_{CCO} = 0 V$ | [2] _ | | 1.7 | - | - | - | pF |
| | capacitance | 2Y, 3Y enabled; $V_O = GND$; $V_{CCO} = 0 V$ | [2] _ | | 1.7 | - | - | - | pF |
| | | 2Y, 3Y disabled; $V_{CCO} = 0 V$ to 2.7 V; $V_O = GND$ or V_{CCO} | [2] _ | | 1.5 | - | - | - | pF |

[1] V_{CCI} is the supply voltage associated with the input pin.

[2] V_{CCO} is the supply voltage associated with the output pin.

[3] For V_{CCI} values not specified in the data sheet: minimum V_{IH} = $0.7 \times V_{CCI}$ and maximum V_{IL} = $0.3 \times V_{CCI}$.

[4] To show I_{CC} remains very low when the input-disable feature is enabled.

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11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 5.

| Symbol | Parameter | Conditions | | | 25 °C | | −40 °C 1 | to +85 °C | Unit |
|----------------------|--------------------------------------|---|------------|-----|--------|------|-----------------|-----------|------|
| | | | | Min | Typ[1] | Max | Min | Max | |
| C _L = 5 p | F | | | | | | | | |
| t _{pd} | propagation delay | A to 2Y, 3Y; see Figure 3 | [2] | | | | | | |
| | | $V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 1.9 | 3.2 | 4.5 | 1.7 | 5.0 | ns |
| | | $V_{CC(B)}$ = 2.3 V to 2.7 V | | 1.5 | 2.6 | 3.4 | 1.3 | 3.8 | ns |
| | | nOE to 1Y; see Figure 3 | | | | | | | |
| | | $V_{CC(A)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.4 | 4.0 | 5.4 | 2.2 | 6.0 | ns |
| | | $V_{CC(A)}$ = 2.3 V to 2.7 V | | 2.2 | 3.2 | 3.9 | 2.0 | 4.3 | ns |
| C _L = 10 | pF | | | | | | | | |
| t _{pd} | propagation delay | A to 2Y, 3Y; see Figure 3 | [2] | | | | | | |
| | | $V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.3 | 3.8 | 5.3 | 2.0 | 5.8 | ns |
| | | $V_{CC(B)}$ = 2.3 V to 2.7 V | | 1.8 | 3.2 | 4.1 | 1.5 | 4.5 | ns |
| | | nOE to 1Y; see Figure 3 | | | | | | | |
| | | $V_{CC(A)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.9 | 4.6 | 6.1 | 2.5 | 6.7 | ns |
| | | $V_{CC(A)} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 2.5 | 3.7 | 4.6 | 2.2 | 5.0 | ns |
| C _L = 5 p | F; V _{CC(A)} = 1.65 V to 1 | .95 V | | | | | | | |
| t _{en} | enable time | nOE to 2Y, 3Y; see Figure 4 | <u>[3]</u> | | | | | | |
| | | $V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.4 | 4.4 | 9.7 | 2.1 | 10.1 | ns |
| | | $V_{CC(B)}$ = 2.3 V to 2.7 V | | 2.2 | 3.9 | 8.2 | 1.9 | 8.8 | ns |
| t _{dis} | disable time | nOE to 2Y, 3Y; see Figure 4 | <u>[4]</u> | | | | | | |
| | | $V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.4 | 4.5 | 8.9 | 2.1 | 9.4 | ns |
| | | $V_{CC(B)}$ = 2.3 V to 2.7 V | | 2.2 | 3.8 | 7.8 | 1.9 | 8.4 | ns |
| C _L = 5 p | F; V _{CC(A)} = 2.3 V to 2.7 | 7 V | | | | | | | |
| t _{en} | enable time | nOE to 2Y, 3Y; see Figure 4 | <u>[3]</u> | | | | | | |
| | | $V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.4 | 4.0 | 8.7 | 2.1 | 9.0 | ns |
| | | $V_{CC(B)}$ = 2.3 V to 2.7 V | | 2.2 | 3.4 | 7.2 | 1.9 | 7.7 | ns |
| t _{dis} | disable time | nOE to 2Y, 3Y; see Figure 4 | <u>[4]</u> | | | | | | |
| | | $V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.4 | 4.2 | 7.9 | 2.1 | 8.3 | ns |
| | | $V_{CC(B)}$ = 2.3 V to 2.7 V | | 2.2 | 3.5 | 6.8 | 1.9 | 7.3 | ns |
| C _L = 10 | pF; V _{CC(A)} = 1.65 V to | 1.95 V | | | | | | | |
| t _{en} | enable time | nOE to 2Y, 3Y; see Figure 4 | [3] | | | | | | |
| | | $V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.9 | 4.9 | 11.0 | 2.5 | 11.7 | ns |
| | | $V_{CC(B)}$ = 2.3 V to 2.7 V | | 2.5 | 4.4 | 9.7 | 2.2 | 10.5 | ns |
| t _{dis} | disable time | nOE to 2Y, 3Y; see Figure 4 | <u>[4]</u> | | | | | | |
| | | $V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.9 | 5.6 | 10.8 | 2.5 | 11.5 | ns |
| | | $V_{CC(B)}$ = 2.3 V to 2.7 V | | 2.5 | 4.6 | 9.5 | 2.2 | 10.1 | ns |
| | | | | | | | | | |

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| Symbol | Parameter | Conditions | Conditions | | 25 °C | | | to +85 °C | Unit |
|----------------------|--------------------------------------|---|------------|-----|--------|------|-----|-----------|------|
| | | | | Min | Typ[1] | Max | Min | Max | |
| C _L = 10 | pF; V _{CC(A)} = 2.3 V to 2. | 7 V | | | | | | | |
| t _{en} | enable time | nOE to 2Y, 3Y; see Figure 4 | [3] | | | | | | |
| | | $V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.9 | 4.5 | 10.0 | 2.5 | 10.5 | ns |
| | | $V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 2.5 | 3.9 | 8.7 | 2.2 | 9.3 | ns |
| t _{dis} | disable time | nOE to 2Y, 3Y; see Figure 4 | [4] | | | | | | |
| | | $V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.9 | 5.3 | 9.8 | 2.5 | 10.3 | ns |
| | | $V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 2.5 | 4.3 | 8.4 | 2.2 | 8.9 | ns |
| C _L = 5 p | F and 10 pF | | | | | | | | |
| C _{PD} | power dissipation capacitance | per active output; output 2Y, 3Y; f _i = 1 MHz; V _I = 0 V to V _{CC} | <u>[5]</u> | | | | | | |
| | | $V_{CC(A)} = V_{CC(B)} = 1.8 V$ | | - | 3.0 | - | - | - | pF |
| | | $V_{CC(A)} = V_{CC(B)} = 2.5 V$ | | - | 3.6 | - | - | - | pF |

Table 8. Dynamic characteristics ... continued

[1] All typical values are measured at nominal $V_{CC(A)}$ and $V_{CC(B)}$.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] t_{en} is the same as t_{PZH} and t_{PZL} .

[4] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $\mathsf{P}_{\mathsf{D}} = \mathsf{C}_{\mathsf{P}\mathsf{D}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}{}^2 \times \mathsf{f}_i \times \mathsf{N} + \Sigma(\mathsf{C}_{\mathsf{L}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}{}^2 \times \mathsf{f}_o) \text{ where:}$ f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = load capacitance in pF;

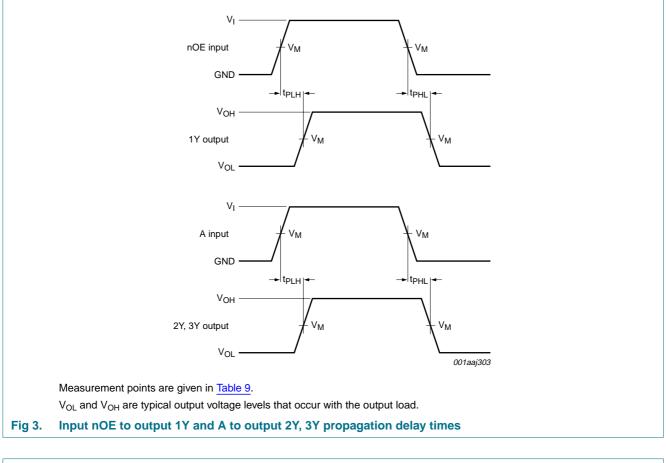
 V_{CC} = supply voltage in V;

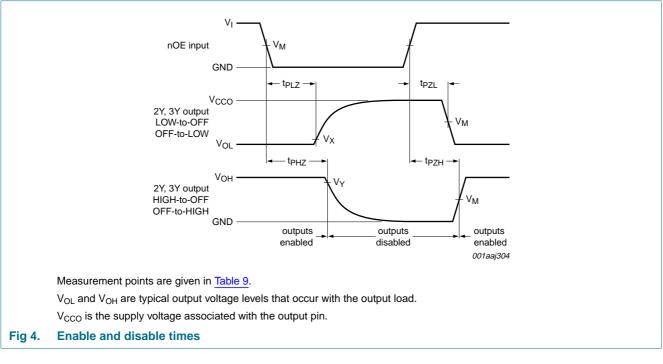
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

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12. Waveforms





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| Table 9. Measurement points | | | | |
|---|---------------------|-----------------------|--------------------------|--------------------------|
| Supply voltage Input ^[1] | | Output ^[2] | | |
| V _{CC(A)} , V _{CC(B)} | V _M | V _M | V _X | V _Y |
| 1.65 V to 2.7 V | 0.5V _{CCI} | $0.5V_{CCO}$ | V _{OL} + 0.15 V | V _{OH} – 0.15 V |

[1] V_{CCI} is the supply voltage associated with the data input port.

[2] V_{CCO} is the supply voltage associated with the output port.

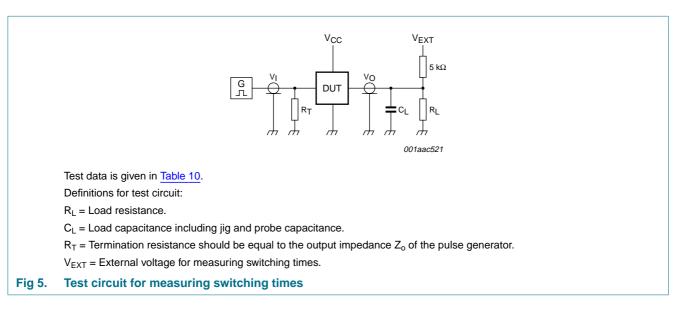


Table 10. Test data

| Supply voltage | Input | | Load ^[2] | | V _{EXT} | | |
|---|--------------------|-----------------------------------|---------------------|------------------------------|-------------------------------------|-------------------------------------|---|
| V _{CC(A)} , V _{CC(B)} | V _I [1] | $\mathbf{t}_{r} = \mathbf{t}_{f}$ | CL | RL ^[3] | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} [4] |
| 1.65 V to 2.7 V | V _{CCI} | \leq 3.0 ns | 5 pF, 10 pF | 5 k Ω or 1 M Ω | open | GND | 2V _{CCO} |

[1] V_{CCI} is the supply voltage associated with the data input port.

[2] For measuring enable and disable times, C_L and R_L are connected to pin 2Y and 3Y.

[3] For measuring enable and disable times $R_L = 5 \text{ k}\Omega$, for measuring propagation delays $R_L = 1 \text{ M}\Omega$.

[4] V_{CCO} is the supply voltage associated with the output port.

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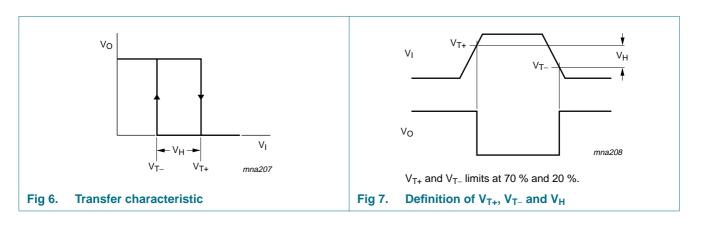
13. Transfer characteristics

Table 11. Transfer characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Figure 5.

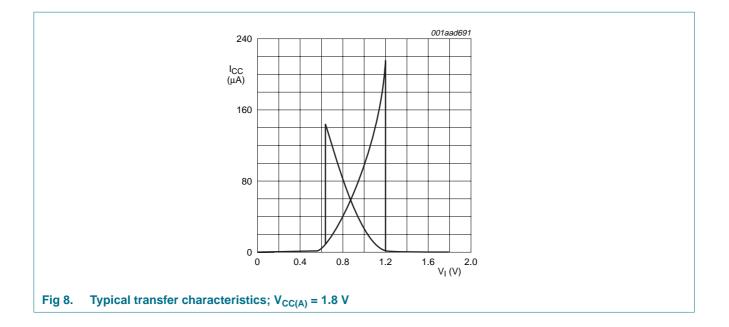
| Symbol | Parameter | Conditions | | 25 °C | | | –40 °C to +85 °C | |
|---|---|--|------|-------|------|------|------------------|---|
| | | | Min | Тур | Max | Min | Max | |
| V _{T+} positive-going threshold voltage | positive-going threshold voltage | nOE inputs; see <u>Figure 6</u> and <u>Figure 7</u> | · | | | | | |
| | | V _{CC(A)} = 1.65 V | 0.91 | - | 1.29 | 0.91 | 1.29 | V |
| | | $V_{CC(A)} = 2.3 V$ | 1.37 | - | 1.77 | 1.37 | 1.77 | V |
| V _{T-} negative-going threshold voltage | | nOE inputs; see <u>Figure 6</u> and <u>Figure 7</u> | | | | | | |
| | | V _{CC(A)} = 1.65 V | 0.47 | - | 0.84 | 0.47 | 0.84 | V |
| | $V_{CC(A)} = 2.3 V$ | 0.69 | - | 1.04 | 0.69 | 1.04 | V | |
| V _H hysteresis voltage | nOE inputs; (V _{T+} – V _T _); see <u>Figure 6</u> , <u>Figure 7</u> and <u>Figure 8</u> | | | | | | | |
| | | V _{CC(A)} = 1.65 V | 0.27 | - | 0.66 | 0.27 | 0.66 | V |
| | | $V_{CC(A)} = 2.3 V$ | 0.53 | - | 0.92 | 0.53 | 0.92 | V |

14. Waveforms transfer characteristics



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15. Package outline

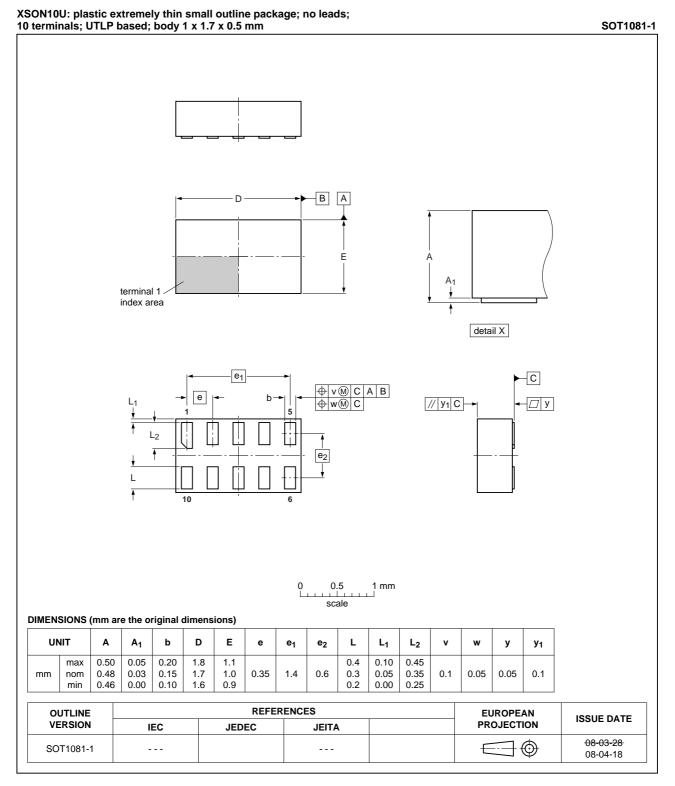


Fig 9. Package outline SOT1081-1 (XSON10U)

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16. Abbreviations

| Table 12. | ble 12. Abbreviations | | |
|-----------|---|--|--|
| Acronym | Description | | |
| CDM | Charged Device Model | | |
| CMOS | Complementary Metal-Oxide Semiconductor | | |
| DUT | Device Under Test | | |
| ESD | ElectroStatic Discharge | | |
| HBM | Human Body Model | | |
| MM | Machine Model | | |
| TTL | Transistor-Transistor Logic | | |

17. Revision history

| Table 13. Revision history | | | | |
|----------------------------|--------------|--------------------|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| 74AUP2T1326_1 | 20090701 | Product data sheet | - | - |

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18. Legal information

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| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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